

$I_{F(AV)} = 10\text{Amp}$   
 $V_R = 35\text{-}45\text{V}$

**Major Ratings and Characteristics**

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	10	A
$I_{FRM}$ @ $T_C = 135^\circ\text{C}$	20	A
$V_{RRM}$	35-45	V
$I_{FSM}$ @ $t_p = 5\ \mu\text{s}$ sine	1060	A
$V_F$ @ 10 Apk, $T_J = 125^\circ\text{C}$	0.57	V
$T_J$ range	-65 to 150	$^\circ\text{C}$

**Description/ Features**

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

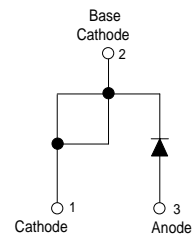
- 150°C  $T_J$  operation
- TO-220 and D<sup>2</sup>Pak packages
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)

**Case Styles**

MBR10..PbF



TO-220AC



Voltage Ratings

Part number	MBR1035PbF	MBR1045PbF
$V_R$ Max. DC Reverse Voltage (V)	35	45
$V_{RWM}$ Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	Values	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	10	A	@ $T_C = 135^\circ\text{C}$ (Rated $V_R$ )
$I_{FRM}$ Peak Repetitive Forward Current	20	A	Rated $V_R$ , square wave, 20kHz $T_C = 135^\circ\text{C}$
$I_{FSM}$ Non Repetitive Peak Surge Current	1060	A	5 $\mu\text{s}$ Sine or 3 $\mu\text{s}$ Rect. pulse Following any rated load condition and with rated $V_{RWM}$ applied Surge applied at rated load conditions halfwave, single phase, 60Hz
	150		
$E_{AS}$ Non-Repetitive Avalanche Energy	8	mJ	$T_J = 25^\circ\text{C}$ , $I_{AS} = 2$ Amps, $L = 4$ mH
$I_{AR}$ Repetitive Avalanche Current	2	A	Current decaying linearly to zero in 1 $\mu\text{sec}$ Frequency limited by $T_J$ max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	Values	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop (1)	0.84	V	@ 20A $T_J = 25^\circ\text{C}$
	0.57	V	@ 10A $T_J = 125^\circ\text{C}$
	0.72	V	@ 20A $T_J = 125^\circ\text{C}$
$I_{RM}$ Max. Instantaneous Reverse Current (1)	0.1	mA	$T_J = 25^\circ\text{C}$ Rated DC voltage
	15	mA	$T_J = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold Voltage	0.354	V	$T_J = T_J$ max.
$r_t$ Forward Slope Resistance	17.6	m $\Omega$	
$C_T$ Max. Junction Capacitance	600	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) $25^\circ\text{C}$
$L_S$ Typical Series Inductance	8.0	nH	Measured from top of terminal to mounting plane
dv/dt Max. Voltage Rate of Change (Rated $V_R$ )	10000	V/ $\mu\text{s}$	

(1) Pulse Width < 300 $\mu\text{s}$ , Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	Values	Units	Conditions
$T_J$ Max. Junction Temperature Range	-65 to 150	$^\circ\text{C}$	
$T_{stg}$ Max. Storage Temperature Range	-65 to 175	$^\circ\text{C}$	
$R_{thJC}$ Max. Thermal Resistance Junction to Case	2.0	$^\circ\text{C/W}$	DC operation
$R_{thCS}$ Typical Thermal Resistance Case to Heatsink	0.50	$^\circ\text{C/W}$	Mounting surface, smooth and greased Only for TO-220
wt Approximate Weight	2 (0.07)	g (oz.)	
T Mounting Torque	Min. 6 (5)	Kg-cm (lbf-in)	
	Max. 12 (10)		
Marking Device	MBR1045		

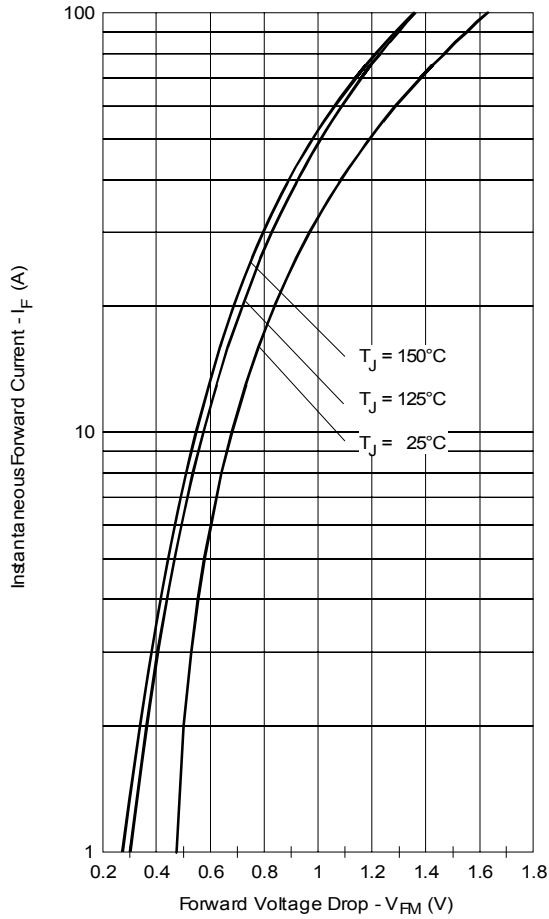


Fig. 1 - Max. Forward Voltage Drop Characteristics

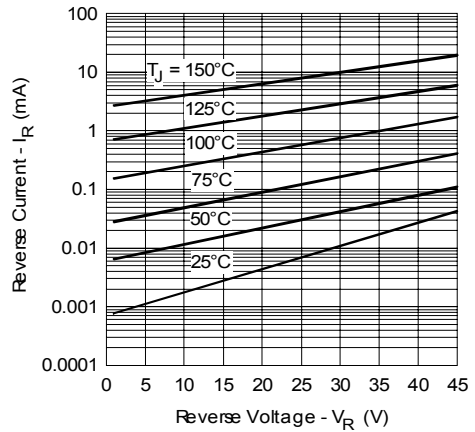


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

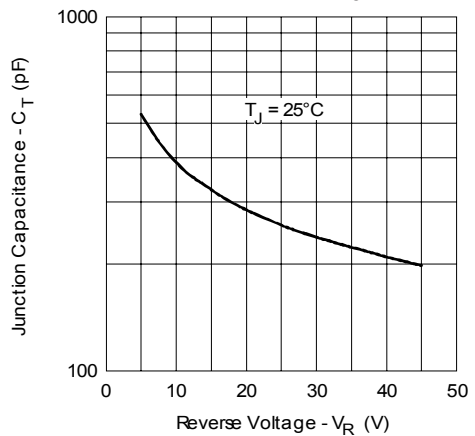


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

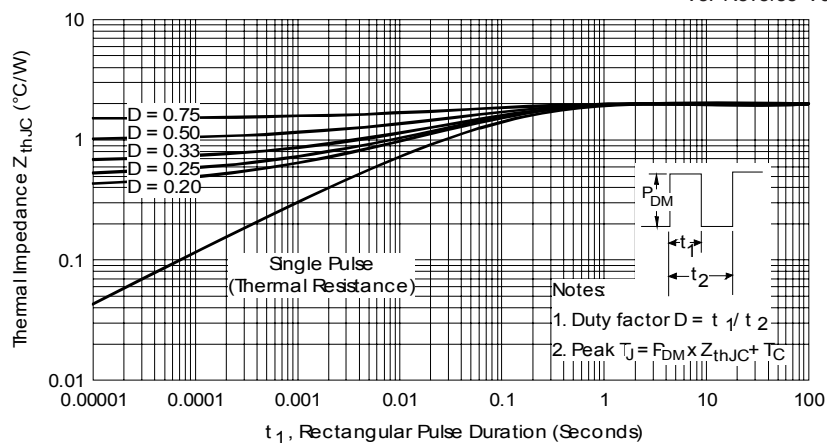


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics

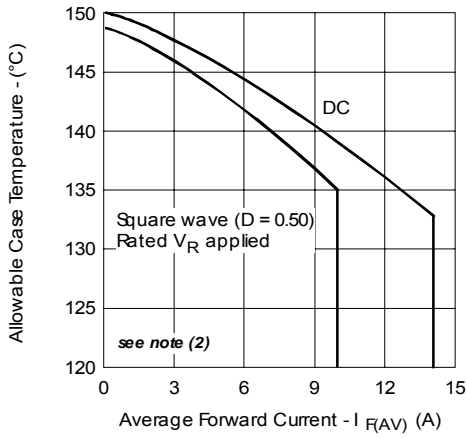


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

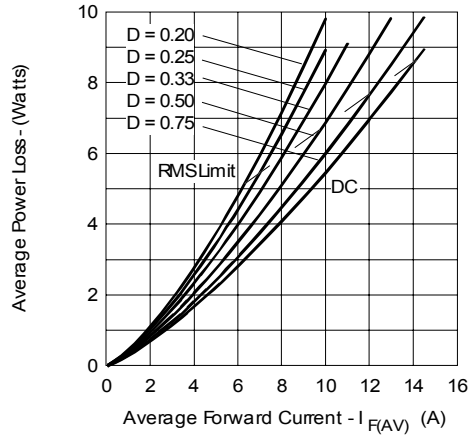


Fig. 6 - Forward Power Loss Characteristics

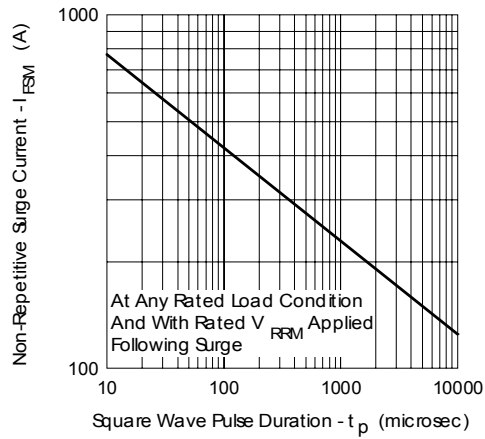


Fig. 7 - Max. Non-Repetitive Surge Current

(2) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);  
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$ ;  $I_R @ V_{R1} = \text{rated } V_R$

Outline Table

NOTES:  
 1- DIMENSIONING AND TOLERANCING AS PER ASME Y14.5 M- 1994  
 2- DIMENSIONS ARE SHOWN IN INCHES (MILLIMETERS)  
 3- LEAD DIMENSION AND FINISH UNCONTROLLED IN L1  
 4- DIMENSION Q, Q1 & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.  
 DIMENSION Q1, Q2 & E1 APPLY TO BASE METAL ONLY.  
 5- CONTROLLING DIMENSION : INCHES.  
 6- THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS E1, D2 & E1  
 7- DIMENSION E2 x H1 DEFINE A ZONE WHERE STAMPING AND SOLDERING IRREGULARITIES ARE ALLOWED.  
 8- OUTLINE CONFORMS TO JEDEC TO-220, D2 (min) WHERE DIMENSIONS ARE DERIVED FROM THE ACTUAL PACKAGE OUTLINE.

SYMBOL	DIMENSIONS				NOTES
	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	3.56	4.83	.140	.190	
A1	0.51	1.40	.020	.055	
A2	2.03	2.92	.080	.115	
b	0.38	1.01	.015	.040	
b1	0.38	0.97	.015	.038	5
b2	1.14	1.78	.045	.070	
b3	1.14	1.73	.045	.068	5
c	0.36	0.61	.014	.024	
c1	0.36	0.56	.014	.022	5
D	14.22	16.51	.560	.650	4
D1	8.38	9.02	.330	.355	
D2	11.68	12.88	.460	.507	7
E	9.65	10.67	.380	.420	4,7
E1	6.86	8.89	.270	.350	7
E2	-	0.76	-	.030	8
e	2.54 BSC	-	.100 BSC	-	
e1	1.27 BSC	-	.050 BSC	-	
H1	5.84	6.86	.230	.270	7,8
L	12.70	14.73	.500	.580	
L1	-	6.35	-	.250	3
L3	1.78	2.13	.070	.084	
L4	0.76	1.27	.030	.050	3
MP	3.53	3.73	.139	.147	
Q	2.54	3.05	.100	.120	

LEAD ASSIGNMENTS  
 DIODES  
 1-2 - CATHODE  
 3 - ANODE

Conform to JEDEC outline TO-220AC

Part Marking Information

IRXC Assembly Line - SubCon Assembly Line

EXAMPLE: THIS IS A MBR1045  
 LOT CODE 1789  
 ASSEMBLED ON WW 19, 2001  
 IN THE ASSEMBLY LINE "C"

Note: "P" in the beginning of date code indicates "Lead-Free"

IRMX Assembly Line

EXAMPLE: THIS IS A MBR1045  
 LOT CODE 1789  
 ASSEMBLED ON WW 19, 2001  
 IN THE ASSEMBLY LINE "C"

Note: "P" in assembly line position indicates "Lead-Free"

Ordering Information Table

Device Code			
MBR	10	45	PbF
①	②	③	④
<b>1</b>	- Schottky MBR Series		
<b>2</b>	- Current Rating (10 = 10A)		
<b>3</b>	- Voltage Ratings		35 = 35V 45 = 45V
<b>4</b>	-	• none = Standard Production	
		• PbF = Lead-Free	

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MBR1045
*****
* This model has been developed by *
* Wizard SPICE MODEL GENERATOR (1999) *
* (International Rectifier Corporation) *
* Contains Proprietary Information *
*****
* SPICE Model Diode is composed by a *
* simple diode plus paralld VCG2T *
*****
.SUBCKT MBR1045 ANO CAT
D1 ANO 1 DMOD (0.04688)
*Define diode model
.MODEL DMOD D(IS=2.14849701885607E-04A,N=1.50833541375759,BV=52V,
+ IBV=0.431942180477539A,RS= 0.000618816,CJO=1.90645706123736E-08,
+ VJ=2.31227489200037,XTI=2, EG=0.684712841282824)
*****
*Implementation of VCG2T
VX 1 2 DC 0V
R1 2 CAT TRES 1E-6
.MODEL TRES RES(R=1,TC1=-29.9118224426661)
GP1 ANO CAT VALUE={-ABS(I(VX))*(EXP((( -6.195028E-06/-29.91182)*(V(2,CAT)*1E6)/(I(VX)+1E-6)-
1)))+1}*4.475503E-02*ABS(V(ANO,CAT))-1}
*****
.ENDS MBR1045

Thermal Model Subcircuit
.SUBCKT MBR1045 5 1

CTHERM1 5 4 1.40E+00
CTHERM2 4 3 1.46E+01
CTHERM3 3 2 9.30E+01
CTHERM4 2 1 1.69E+03

R THERM1 5 4 5.79E-01
R THERM2 4 3 7.72E-01
R THERM1 3 2 4.45E-01
R THERM1 2 1 1.93E-01

.ENDS MBR1045
    
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Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level and Lead-Free.  
Qualification Standards can be found on IR's Web site.

International  
**IOR** Rectifier

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Visit us at [www.irf.com](http://www.irf.com) for sales contact information. 04/06